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# First-principles calculations of strain engineering in NaYF<sub>4</sub>-based nanocrystals with hydroxyl impurities†

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Lanthanide-based nanocrystals with heterogeneous core–shell structures possess elastic strain due to lattice mismatch and volumetric expansion or shrinkage. Strain relaxation is usually accompanied by lattice defects, especially those point defects and small defect clusters. However, the influence of strain on the formation of lattice defects remains unclear. Using OH<sup>−</sup> ions as a representative lattice impurity, first-principles calculations can be used to address the correlation between the thermodynamic stability of OH-based substitutional defects and elastic strain. Moreover, the concentration of OH<sup>−</sup> impurities in both strained and relaxed sodium yttrium fluoride lattices can be greatly reduced by increasing the concentration of fluoride-containing precursors. These findings suggest that minimal incorporation of OH<sup>−</sup> ions effectively suppresses multiphonon nonradiative relaxation and thus boost the efficiency of upconversion conversion.

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## Introduction

Heteroepitaxial growth techniques have proven effective in regulating the electrical, optical, magnetic, and mechanical pro-

erties of given materials, mainly due to subtle interactions and cooperative efforts of individual constituents.<sup>1–3</sup> Although epitaxial growth of high-quality, coherent heterostructures requires small lattice mismatches (~1%), epitaxial growth for systems with large lattice mismatches (>8%) can be achieved by matching integral multiples of the main crystal facets between the epitaxial layer and the matrix.<sup>4</sup>

Given the slight differences in the cationic radii of the lanthanide series, the epitaxial growth approach has been extensively used to prepare lanthanide-doped core–shell nanocrystals with controlled shell thickness.<sup>5–9</sup> The core–shell engineering not only enhances upconversion efficiency by suppressing surface quenching but also endows nanocrystals with new functionalities that are not available in their bulk counterparts.<sup>10–14</sup>

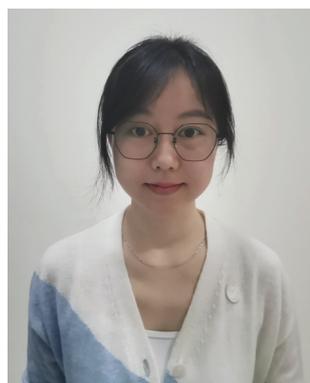
Lattice mismatch between core and shell components plays a central role in dictating the optical response of upconversion nanocrystals.<sup>15–17</sup> This is because the interfacial tension caused by the mismatch contributes to changes in the free energy during heterogeneous nucleation, thereby affecting the quality and crystalline integrity of epitaxial layers. Notably, it has been shown that the mode (compressive or tensile) rather than the magnitude of the mismatch strain determines the growth coherence of shell layers.<sup>18</sup>

Apart from lattice mismatch-induced strains, nanocrystals are also subject to lattice expansion or shrinkage during hydrothermal synthesis. To reach a steady state, elastic strain in nanocrystals may relax to some extent and form lattice defects, especially point defects in small nanocrystals. The formation of defects facilitates ion diffusion between core and shell constituents, thereby resulting in cation mixing in core–shell

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nanocrystals.<sup>19–21</sup> Although various core–shell structures have been constructed using different lanthanide-containing materials, it remains unclear how elastic strain affects lattice integrity and upconversion emission.

Here, we systematically study the influence of elastic strain on the formation and stability of hydroxyl (OH<sup>−</sup>) impurities in cubic-phase NaYF<sub>4</sub> core–shell nanocrystals by first-principles calculations based on density functional theory (DFT). The OH<sup>−</sup> ion was chosen as a model impurity because of its capacity for mediating nonradiative multiphonon relaxation in upconversion nanosystems. We show that OH<sup>−</sup> is incorporated into host lattices with high probability by substituting F<sup>−</sup> ions (OH<sub>F</sub>). Moreover, its concentration increases with the magnitude of elastic tensile loading. In contrast, compressive strain mitigates the formation of such lattice defects. Under fluoride-rich conditions, core–shell nanoparticles with compressive shells can accommodate minimal OH<sub>F</sub> defects, reduce vibrational coupling, and improve excitation energy harvesting for enhanced upconversion luminescence.

## Computational details

First-principles calculations were performed based on DFT implemented in the Vienna *ab initio* package (VASP) with pseudopotentials constructed by the projector-augmented wave methods.<sup>22,23</sup> We used the semi-local generalized gradient approximation in the form of Perdew–Burke–Ernzerhof (GGA-PBE) to characterize electron exchange–correlation interactions.<sup>24</sup> To optimize electronic calculations, 15% of the Hartree–Fock exchange interaction was incorporated into the GGA-PBE functional using the screened-exchange hybrid density functional HSE06.<sup>25</sup>

A 97-atom supercell model was employed to investigate the thermodynamic stability of OH<sub>F</sub> defects in the inner region of a given nanocrystal. Our previous study showed that changes in formation energies of point defects are negligible when the supercell atom increases to 144.<sup>26</sup> *K*-Point samplings of 4 × 4 × 2 and 2 × 2 × 2 Monkhorst–Pack meshes were used for the unit cell and supercell, respectively. A slab model containing 218 atoms was constructed to calculate the formation energy of OH<sub>F</sub> defects on nanocrystal surfaces. Each slab was separated by a 15 Å-thick vacuum layer. A 2 × 2 × 1 Monkhorst–Pack mesh was used for the integrations in the Brillouin zone. For all calculations, the energy cutoff of the plane-wave basis set was set to 520 eV and the energy convergence criterion was set to 1 × 10<sup>−6</sup> eV. Note that lattice constants were fixed during geometry optimization and only atoms were allowed to relax. The optimization was terminated when the maximum residual force at each atom was less than 0.01 eV Å<sup>−1</sup>.

The formation energy of OH<sub>F</sub> defects was given as:<sup>27</sup>

$$E_f = E_D^q - E_P + n\mu_F - n\mu_{OH} + q(\epsilon_F + E_V + \Delta V), \quad (1)$$

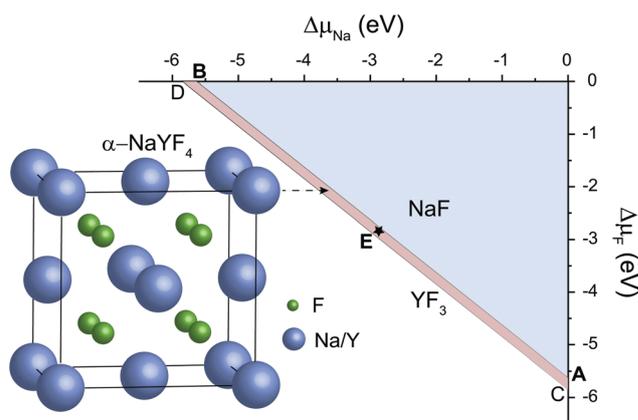
where  $E_D$  is the total energy of a NaYF<sub>4</sub> crystal containing OH<sub>F</sub> defects and  $q$  denotes the charge state of the defect.  $E_P$  is the total energy of the corresponding perfect crystal.  $n$  is the

number of incorporated OH<sup>−</sup> or removed F<sup>−</sup> ions.  $\mu_F$  and  $\mu_{OH}$  denote chemical potentials of fluoride and hydroxyl species, respectively.  $E_V$  is the valence band maximum (VBM) of the perfect crystal, and a  $\Delta V$  correction term is employed to align the potential of the OH<sub>F</sub>-containing crystal with the perfect crystal.  $\epsilon_F$  is the Fermi level, relative to the VBM of the intact crystal.

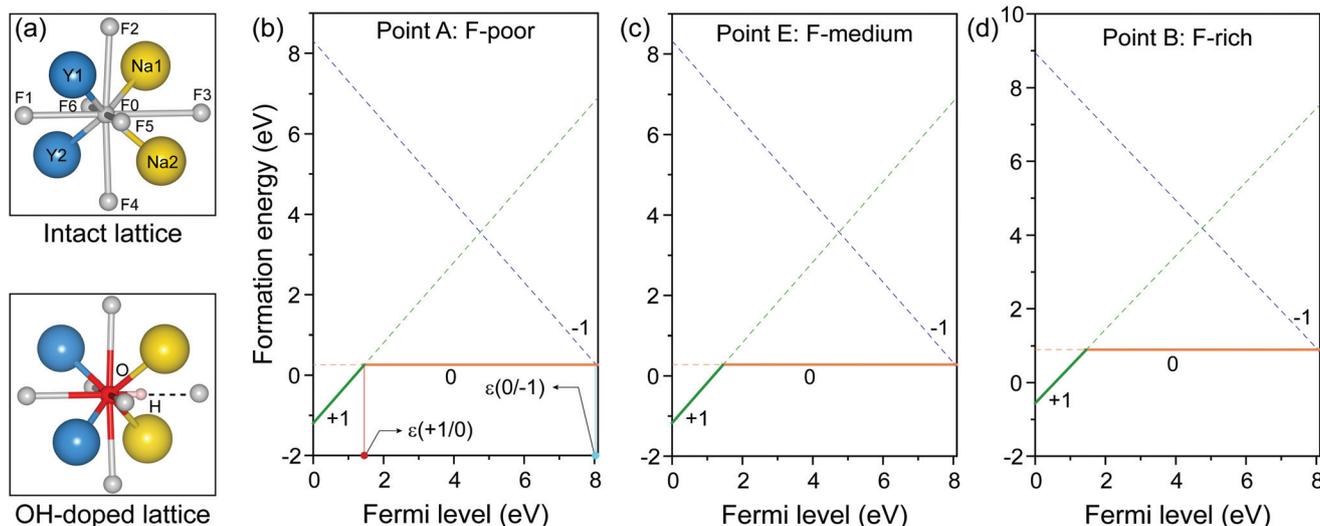
## Results and discussion

As representative lattice defects, hydroxyl impurities have been observed in both core and shell regions of NaYF<sub>4</sub>-based nanocrystals.<sup>28–31</sup> Given their chemical similarity, the substitution of host F<sup>−</sup> ions by OH<sup>−</sup> likely requires low activation energy.<sup>32</sup> To explore the atomic and energetic implications of such substitution, we first estimated a thermodynamic stability diagram of  $\alpha$ -NaYF<sub>4</sub> as a function of the relative chemical potentials of sodium ( $\Delta\mu_{Na}$ ) and fluoride ( $\Delta\mu_F$ ), relative to their elemental substances (ESI and Table S1†). The plotted phase diagram indicates that  $\alpha$ -NaYF<sub>4</sub> is stable only in a narrow range (Fig. 1, pink region). Three representative conditions, namely fluoride-poor (point A), fluoride-medium (point E), and fluoride-rich (point B), are selected to calculate the formation energy of OH<sub>F</sub>.

We first studied the OH<sub>F</sub> formation in the inner region of an unstrained nanocrystal. Optimized atomic structures showed that Na<sup>+</sup> and F<sup>−</sup> ions in the first coordination shell of OH<sup>−</sup> are slightly relaxed outward, except for Y<sup>3+</sup> and F<sup>−</sup>, which forms a hydrogen bond with H<sup>+</sup>, as manifested by the change in bond length (Fig. 2a and Table S2†). Additionally, the O–H bond length shows a minor change compared to that of a free OH<sup>−</sup> ion, suggesting negligible lattice distortion. Plotting the formation energy as a function of chemical potential and Fermi level revealed that the formation energy increases as the synthetic conditions change from F-poor to F-rich (Fig. 2b–d). Notably, neutral OH<sub>F</sub> is stable over a wide range of  $\epsilon_F$ , while



**Fig. 1** Atomic illustration of cubic-phase NaYF<sub>4</sub> and the corresponding thermodynamic stability diagram as a function of the relative chemical potentials of sodium ( $\Delta\mu_{Na}$ ) and fluoride ( $\Delta\mu_F$ ). Points A, E, and B represent three sets of chemical potentials.



**Fig. 2** (a) Optimized first coordination shell of F<sup>-</sup> (upper panel) and OH<sup>-</sup> (lower panel) ions. (b–d) Formation energies of OH<sub>F</sub> defects as a function of Fermi energy under F-poor, F-medium, and F-rich conditions (points A, E, and B in Fig. 1). OH<sub>F</sub> denotes the substitution of F<sup>-</sup> by OH<sup>-</sup>, and  $\epsilon$  is the corresponding thermodynamic transition level.

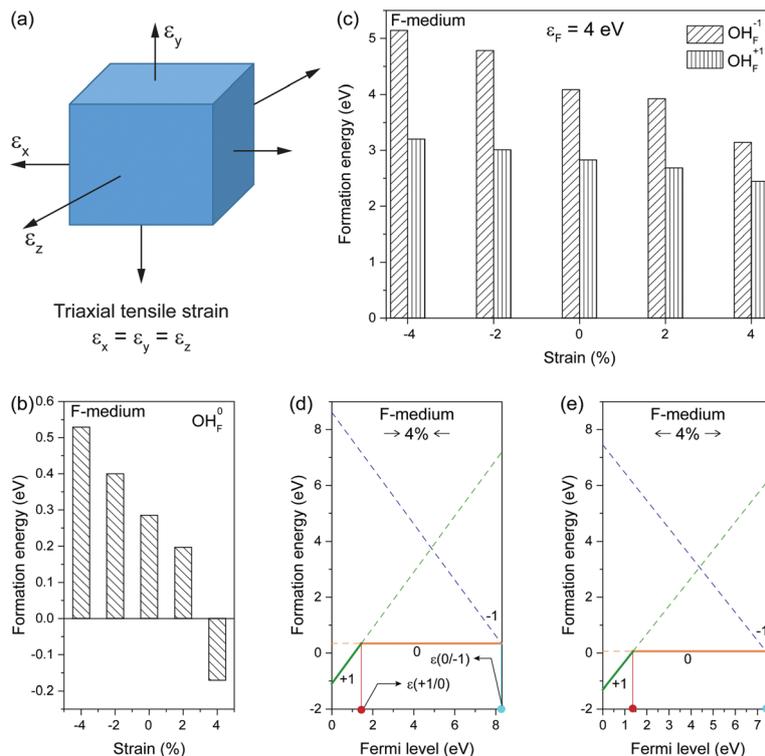
the single positive charge state of OH<sub>F</sub> becomes more stable when  $\epsilon_F$  is close to the host VBM. More specifically, formation energies of neutral OH<sub>F</sub> are 0.264, 0.285, and 0.898 eV, calculated under F-poor, F-medium, and F-rich conditions, respectively. This suggests a facile substitution of OH<sup>-</sup> for F<sup>-</sup> ions under F-poor or F-medium conditions. It is noteworthy that OH<sub>F</sub> can form under F-rich conditions because of its moderate formation energy. On the other hand, conventional synthetic methods for lanthanide-doped fluoride nanocrystals generally require a reaction temperature of  $\sim 300$  °C, which facilitates the replacement of F<sup>-</sup> by OH<sup>-</sup>.<sup>33</sup>

With changes in temperature during synthesis, fluoride nanocrystals can undergo thermal expansion or shrinkage. The mode and magnitude of the corresponding hydrostatic strains depend on the thermal response of host materials. For example, the lattice constant of NaF increases with increasing temperature.<sup>34,35</sup> By comparison, the cubic SrF<sub>3</sub> lattice contracts with increasing temperature.<sup>36</sup> Additionally, the pressure-induced hydrostatic strain has been deliberately applied to lanthanide-containing fluorides, garnets, and oxides for optical modulation.<sup>37–40</sup> To probe the influence of hydrostatic elastic strain on OH<sub>F</sub> formation, we employed a triaxial strain scheme to mimic the expansion and contraction of fluoride lattices (Fig. 3a). Considering that the precursors for NaYF<sub>4</sub> nanocrystal synthesis usually follow the stoichiometry 1 : 1 : 4, we investigated the formation of OH<sub>F</sub> in strained lattices under F-medium conditions unless otherwise stated.

By applying triaxial strain to fluoride crystals, we found that the formation energy of neutral OH<sub>F</sub> increased with increasing compressive loading (Fig. 3b). In contrast, the formation energy decreased when tensile loading was applied. The same trend was observed for both positively and negatively charged OH<sub>F</sub> (Fig. 3c). In addition to changes in formation energy, the position of the thermodynamical transition level  $\epsilon(q/q')$  shifted

in strained lattices. Note that the transition level is defined as the Fermi level at which formation energies of charge states  $q$  and  $q'$  are equal. For illustration, let us consider lattices with 4% compressive and tensile strains. For the compressed lattice, the transition level  $\epsilon(+1/0)$  shifted 0.131 eV toward the host VBM relative to the unconstrained lattice (Fig. 3d). In contrast, the position of  $\epsilon(0/-1)$  remained unchanged. Upon tensile strain, the system exhibited a slight change in  $\epsilon(+1/0)$  (Fig. 3e). Notably,  $\epsilon(0/-1)$  shifted away from the host CBM by 0.164 eV relative to the relaxed lattice, indicative of a negative charge state of OH<sub>F</sub> stabilized by tensile strain. Given the presence of a charge state transition level at  $\sim 1.4$  eV above the host VBM, it is likely that OH<sub>F</sub> defects in rigid fluoride lattice act as nonradiative recombination centers.<sup>41</sup>

When a nanocrystal is epitaxially coated with a thin shell, the shell layer usually adopts a lattice structure commensurate with the core, thereby sustaining either in-plane tensile or compressive strain (Fig. 4a). Unlike hydrostatic strain, strain along the norm of the shell can relax due to the Poisson effect. We thus used a biaxial strain scheme to study the influence of the misfit-induced strain on OH<sub>F</sub> formation (Fig. 4b). Similarly, we found that compressive strain increases formation energy, while tensile stress reduces the formation energy (Fig. 4c). It is worth noting that the influence of biaxial strain on formation energy is less pronounced than the influence of triaxial strain. By way of illustration, formation energies of neutral OH<sub>F</sub> are 0.529, 0.343, and 0.285 eV in fluoride lattices with 4% triaxial tension, biaxial compression, and no strain, respectively. By comparison, formation energies decreased and increased with biaxial compression and tensile strain, respectively. When the tensile strain was applied to shells, the lattice spacing decreased due to lattice contraction along the normal direction, making it difficult to replace F<sup>-</sup> with large OH<sup>-</sup> ions. Given the large interface of a typical



**Fig. 3** (a) Schematic of triaxial tensile strains induced by lattice expansion.  $\epsilon_i$  ( $i = x, y, \text{ or } z$ ) denotes normal strains that are perpendicular to  $yz$ ,  $xz$ , and  $xy$  planes, respectively. (b) Formation energies of neutral  $\text{OH}_F$  defects as a function of strain under F-medium conditions. (c) Formation energies of charged  $\text{OH}_F$  defects as a function of strain under F-medium conditions. (d and e) Formation energies of  $\text{OH}_F$  defects as a function of the Fermi energy under F-medium condition upon 4% compressive or 4% tensile strain, respectively.

20 nm core-shell nanocrystal, the conclusions drawn from the calculations apply not only to the coherent shell but also to the region of the anisotropic shell far from core-shell boundaries.

Considering that neutral  $\text{OH}_F$  is stable over a wide range of  $\epsilon_F$ , we next estimate its concentration as a function of temperature in biaxially strained and unstrained lattices using the calculated formation energy  $E_f$  by:

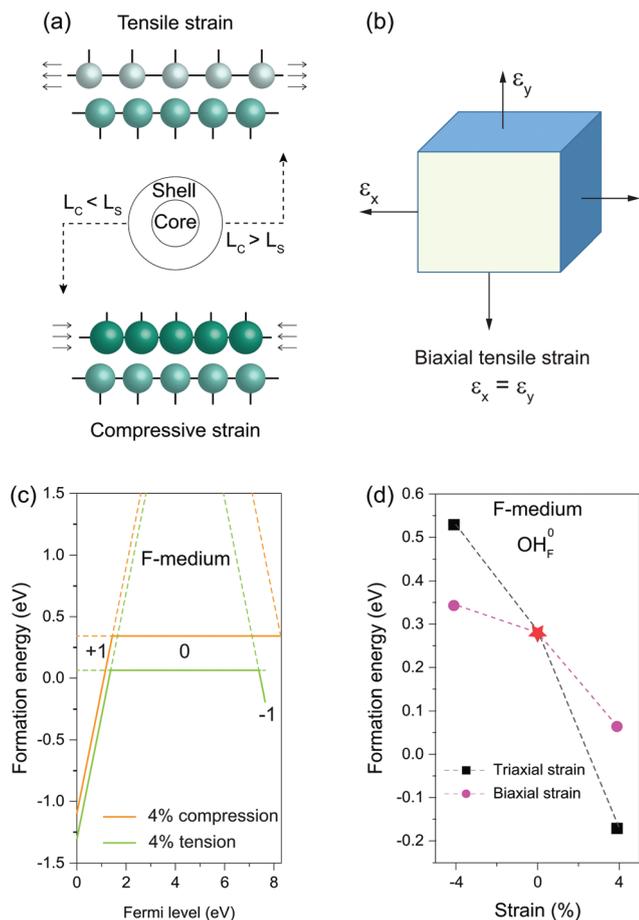
$$c = N_{\text{site}} \exp\left(-\frac{E_f}{kT}\right), \quad (2)$$

where  $N_{\text{site}}$  is the number of sites in the fluoride lattice into which the  $\text{OH}^-$  can be incorporated,  $k$  is the Boltzmann constant, and  $T$  is the temperature.

For nanocrystals synthesized under F-medium conditions, the  $\text{OH}_F$  concentration increased with increasing temperature. Compared with an unstrained lattice, thin shells subjected to biaxial tensile strain contain more  $\text{OH}_F$  defects, while biaxially compressed shells contain fewer  $\text{OH}_F$  defects (Fig. 5a). For example, the calculated  $\text{OH}_F$  concentrations at 300 °C are  $3.6 \times 10^{18}$ ,  $1.2 \times 10^{20}$ , and  $1.3 \times 10^{22} \text{ cm}^{-3}$  in 4% compressed, unstrained, and stretched lattices, respectively. Analogously, the synthetic condition has a great utility for determining the concentration of  $\text{OH}_F$  defects. If we take neutral  $\text{OH}_F$  in the relaxed lattice for illustration, the  $\text{OH}_F$  concentration increased by six orders of magnitude when the F-poor or F-medium to

F-rich conditions were varied (Fig. 5b). Specifically, the calculated  $\text{OH}_F$  concentrations at 300 °C are  $1.9 \times 10^{20}$ ,  $1.2 \times 10^{20}$ , and  $3.2 \times 10^{14} \text{ cm}^{-3}$  under F-poor, F-medium, and F-rich conditions, respectively. For an unstrained 25 nm nanocrystal synthesized under F-medium conditions, the number of incorporated  $\text{OH}^-$  ions is  $\sim 980$ . This estimated  $\text{OH}_F$  concentration could be used to generate geometric descriptors for crystal structures, enabling defect-bound theoretical estimation of intensity parameters associated with 4f-4f transitions.<sup>42,43</sup>

Using slab models, we investigated the stability of neutral  $\text{OH}_F$  on  $\alpha\text{-NaYF}_4$  nanocrystal surfaces. The (110) surface was chosen for its high stability, which is enabled by a stoichiometric arrangement of anions and cations in each plane.<sup>44</sup> Optimized atomic structures showed a tilted O-H bond pointing toward a neighbouring  $\text{F}^-$  ion, due to the formation of hydrogen bonds (Fig. 6a). The calculated formation energies of  $\text{OH}_F$  at the surface under three representative conditions are much smaller than those of  $\text{OH}_F$  in the interior, suggesting that  $\text{OH}^-$  ions are more prone to substitute  $\text{F}^-$  on the surface. Notably, we obtained negative formation energies for  $\text{OH}_F$  under F-poor and F-medium conditions (Fig. 6b). This implies a spontaneous formation of  $\text{OH}_F$  on nanocrystal surfaces, and nanocrystals might be unstable in the presence of such defects. As such, tensile loading of the surface may lead to a high concentration of  $\text{OH}_F$  on the surface.



**Fig. 4** (a) Schematic of tensile and compressive strains induced by lattice mismatch between the core and shell regions.  $L_c$  and  $L_s$  denote the lattice constants of the core and shell components, respectively. (b) Schematic biaxial tensile strain. (c) Formation energies of  $\text{OH}_F$  defects as a function of the Fermi energy under F-medium conditions upon 4% compressive or 4% tensile strain. (d) Formation energies of neutral  $\text{OH}_F$  defects as a function of triaxial or biaxial strains under F-medium conditions.

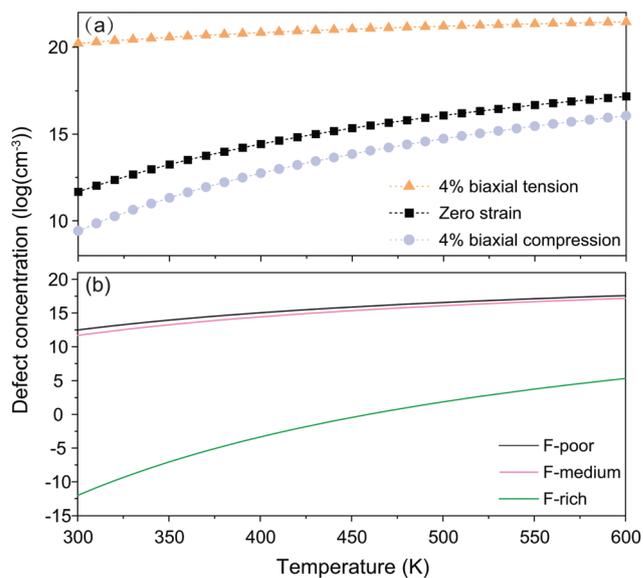
$\text{OH}^-$  is often considered detrimental to upconversion luminescence because it can effectively deactivate excited lanthanide ions through nonradiative multiphonon decay *via* electronic-to-vibrational energy transfer. The probability of multiphonon relaxation between two states of a lanthanide ion can be estimated by:<sup>45,46</sup>

$$W_{\text{MR}} = B \times e^{-\alpha P}, \quad (3)$$

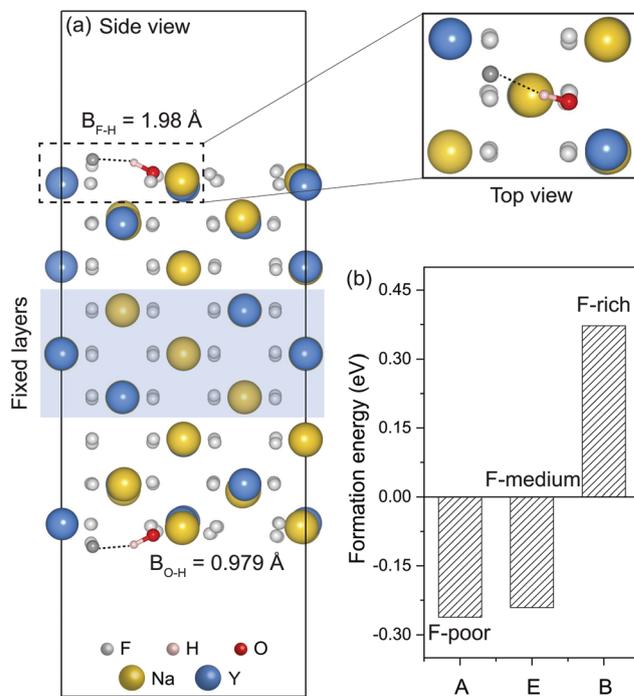
where  $B$  and  $\alpha$  are host-dependent parameters.  $P$  is the number of phonons required to bridge the energy gap  $\Delta E$  between these two states. The correlation between  $P$  and  $\Delta E$  is given by:

$$P = \frac{\Delta E}{\hbar\omega}, \quad (4)$$

where  $\hbar\omega$  is the maximum phonon energy of a given host.



**Fig. 5** (a) Concentrations of neutral  $\text{OH}_F$  defects (under different strains) as a function of temperature under F-medium conditions. (b) Concentrations of neutral  $\text{OH}_F$  defects (strain-free) as a function of temperature under three representative conditions.



**Fig. 6** (a) Optimized atomic structure of  $\alpha\text{-NaYF}_4$  (110) surface containing neutral  $\text{OH}_F$  defects. (b) Formation energies of the corresponding  $\text{OH}_F$  defects under three representative conditions.  $B_{\text{F-H}}$  and  $B_{\text{O-H}}$  denote the length of F–H and O–H bonds, respectively.

For  $\text{NaYF}_4$  nanocrystals with high  $\text{Yb}^{3+}$  dopant contents, the average distance between  $\text{OH}^-$  and  $\text{Yb}^{3+}$  is shorter than that between  $\text{OH}^-$  and lanthanide activators. We thereby use  $\text{Yb}^{3+}$

as a model ion to calculate the multiphonon relaxation probability. Given the high-energy stretching vibration of the O–H bonds ( $\sim 3500\text{ cm}^{-1}$ ), the energy gap between the  $^2F_{5/2}$  and  $^2F_{7/2}$  states of  $\text{Yb}^{3+}$  ( $\sim 10\,204\text{ cm}^{-1}$ ) can be bridged by three phonons. Considering that multiphonon relaxation, in which less than five phonons are emitted, can effectively compete with radiative decays,  $\text{OH}^-$  can largely quench the neighboring excited  $\text{Yb}^{3+}$  ions and reduce upconversion efficiency. For the intact  $\text{NaYF}_4$  lattice with a phonon energy of  $\sim 350\text{ cm}^{-1}$ , multiphonon-induced deactivation of  $\text{Yb}^{3+}$  ions hardly occurs because of the emission of 29 phonons.<sup>47</sup> Specifically, the presence of  $\text{OH}^-$  enhances the probability of nonradiative multiphonon relaxation by a factor of  $2.0 \times 10^{11}$ . Note that  $\text{OH}^-$ -induced deactivation of  $\text{Yb}^{3+}$  ions has been demonstrated to be responsible for water-associated luminescence quenching in  $\text{Yb}$ -sensitized upconversion nanocrystals.<sup>48</sup>

Although  $\text{OH}^-$ -mediated surface quenching can be effectively suppressed by shell passivation, the calculated moderate formation energy suggests that internal  $\text{OH}_\text{F}$  can be readily formed, especially under F-poor conditions. The presence of internal  $\text{OH}^-$  ions has also been experimentally observed, as manifested by the Fourier-transform infrared spectroscopy signal near  $3400\text{ cm}^{-1}$ .<sup>29</sup> In that regard,  $\text{OH}^-$  ions can be incorporated into the shell lattice. It has been shown that coherent growth of lanthanide-based core–shell nanocrystals results in a tensile-strained shell.<sup>18</sup> Taken together, the  $\text{OH}_\text{F}$  concentration in the shell is expected to be higher than that in the core region because biaxial tensile strain reduces the formation energy of  $\text{OH}_\text{F}$ . Although lanthanides are spatially confined in the core, the vibronic coupling between the lanthanides in the core and the  $\text{OH}_\text{F}$  in the shell could remain strong, mainly due to the small shell thickness ( $\sim 2\text{ nm}$ ) and long-range electronic-to-vibrational energy transfer.<sup>49</sup>

Conversely, compressive strain in the shell may reduce  $\text{OH}_\text{F}$  concentration due to increased formation energy. However, shell growth under compression are neither coherent nor complete, which severely limits the effectiveness of shell passivation.<sup>18</sup> For instance, epitaxial coating of  $\beta\text{-NaYbF}_4$  could only be achieved with  $\text{NaLuF}_4$  and  $\text{NaYF}_4$ .<sup>50</sup> This is because other  $\text{NaNLnF}_4$  ( $\text{Ln} = \text{lanthanide}$ ) compositions can induce compressive strain when applied to  $\text{NaYbF}_4$  surfaces. On the other hand, the  $\text{OH}_\text{F}$  concentration in both core and shell lattices can be greatly reduced when synthesized under F-rich conditions. Hence, it is believed that the  $\text{OH}_\text{F}$  concentration in the core–shell nanocrystals with low-compression mismatch can reach a minimum when the fluoride content is increased during preparation.

It is noteworthy that the Gibbs free energies of the systems under study were approximated to the total energies obtained directly from DFT-based electronic calculations. Consequently, the calculated formation energy does not take into account the contribution of configurational entropy, vibrational entropy, and volume of formation. A simple dimensional analysis indicates a negligible contribution ( $\sim 0.1\text{ meV \AA}^{-3}$ ) from the volume term, even at pressures up to 100 atm. Given the low concentration of  $\text{OH}^-$  and the well-ordered supercells, the esti-

mated contribution of configurational entropy is less than 0.1 meV per substitution site when the temperature falls in the range between 300 and 570 K. Moreover, the contribution of vibrational entropy has reportedly become significant at high temperatures (e.g., 1000 K).<sup>51</sup> Taken together, the total energy obtained from the DFT calculation is a dominant term, and the atomistic thermodynamics approach can offer a rapid prediction of the trend of defect formation in certain materials.<sup>52,53</sup>

## Conclusions

In summary, we have systematically investigated the influence of elastic strain on the formation of  $\text{OH}_\text{F}$  defects in fluoride-based nanocrystals using first-principles calculations. The calculations show that both the mode and the magnitude of the strain determine the formation of  $\text{OH}_\text{F}$ . For a lattice under tensile strain, the concentration of  $\text{OH}_\text{F}$  defects is likely higher than that of the relaxed counterparts because of lower formation energies. In contrast, the formation of  $\text{OH}_\text{F}$  can be suppressed by compressive strain. The  $\text{OH}_\text{F}$  concentration can be greatly reduced when lanthanide-doped nanocrystals are prepared under F-rich conditions instead of F-poor or F-medium conditions. These findings not only provide insights into the thermodynamic stability of  $\text{OH}_\text{F}$  defects in fluoride-based nanocrystals but also offer guidance for the fabrication of bright upconversion nanocrystals through strain engineering.

## Author contributions

X. Q. and X. L. conceived the project, discussed the results, and wrote the manuscript. X. Q. conducted the quantum mechanical calculations.

## Conflicts of interest

The authors declare no competing interests.

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